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CLS 029

EBR 6 Amp Epoxy Bridge Rectifiers

VH Series

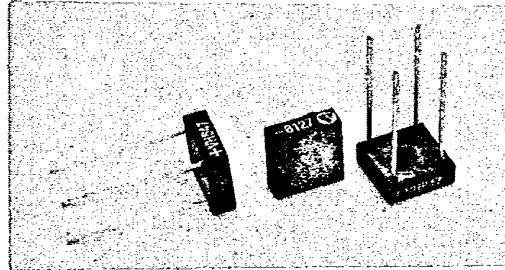
January 1984

Glass Passivated Silicon Chips

Controlled Avalanche Series with 250V, 450V, 650V, and 850V Minimum Avalanche Ratings

Non-Controlled Avalanche Series with 50V, 100V, 200V, 400V, 600V, 800V, and 1000V V_{RRM} Ratings

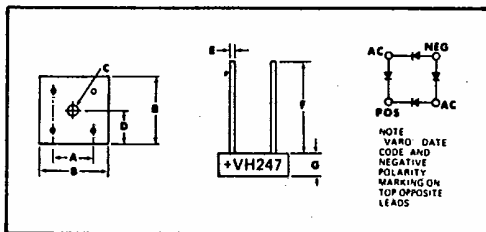
100 Amps Peak One Half Cycle Surge Current



MAXIMUM RATINGS AT $T_A = 25^\circ\text{C}$ (Unless Otherwise Specified)	SYMBOL	CONTROLLED AVALANCHE				NON-CONTROLLED AVALANCHE						UNITS		
		VH247	VH447	VH647	VH847	VH048	VH148	VH248	VH448	VH648	VH848		VH1048	
DC Blocking Voltage	V_{RM}	200	400	600	800	50	100	200	400	600	800	1000	Volts	
Working Peak Reverse Voltage	V_{RWM}	200	400	600	800	50	100	200	400	600	800	1000	Volts	
Peak Repetitive Reverse Voltage	V_{RRM}	200	400	600	800	50	100	200	400	600	800	1000	Volts	
RMS Reverse Voltage	$V_{R(RMS)}$	140	280	420	560	35	70	140	280	420	560	700	Volts	
Power Dissipation in $V_{(BR)}$ Region for 100 μsec Square Wave	P_{RM}	400				NA						Watts		
Continuous Power Dissipation in $V_{(BR)}$ Region at $T_{HS} = 80^\circ\text{C}$	P_R	2				NA						Watts		
Fusing Data	I^2t							40						Amps ² Sec.
Peak Surge Current, 1/2 Cycle at 60 Hz, (Non-Rep) and $T_{HS} = 80^\circ\text{C}$ (Fig. 2)	I_{FSM}							100						Amps
Peak Surge Current, 1 sec. at 60 Hz and $T_{HS} = 80^\circ\text{C}$ (Fig. 2)	I_{FRM}							25						Amps
Avg. Forward Current at $T_{HS} = 80^\circ\text{C}$ (Fig. 1)	I_D							6						Amps
Junction Operating and Storage Temperature Range.	T_J, T_{STG}							50 to +150						$^\circ\text{C}$
Maximum soldering temperature and time								10 Seconds at 265°C						

ELECTRICAL CHARACTERISTICS (At $T_A = 25^\circ\text{C}$ (Unless Otherwise Specified))	SYMBOL	CONTROLLED AVALANCHE				NON-CONTROLLED AVALANCHE						UNITS		
		VH247	VH447	VH647	VH847	VH048	VH148	VH248	VH448	VH648	VH848		VH1048	
Minimum Avalanche Voltage, -	$V_{(BR)}$	250	450	650	850	NA						Volts		
Maximum Avalanche Voltage	$V_{(BR)}$	700	900	1100	1300	NA						Volts		
Maximum Instantaneous Forward Voltage Drop (per diode) at 6 Amps (Fig. 3)	V_{FM}							1.3						Volts/Leg
Maximum Reverse Current at Rated V_{RM}	I_{RM}							5						μA
Maximum Reverse Current at Rated V_{RM} at $T_J = 125^\circ\text{C}$	I_{RM}							1.0						MA
Insulation Strength From Circuit to Case (min.)								2000						Volts DC
Thermal Resistance (Typ) Junction to case (on heat sink)	RO_{JC}							6						$^\circ\text{C}/\text{W}$
Junction to air (no heat sink)	RO_{JA}							25						$^\circ\text{C}/\text{W}$

Part Nos. VH247, VH447, VH647, VH847, VH048, VH148, VH248, VH448, VH648, and VH848 have been recognized under the Component Program of Underwriters Laboratories, Inc.



LTR	INCHES	MILLIMETERS
A	.411 - .441	10.44 - 11.20
B	.590 - .610	14.99 - 15.49
C	.137 - .167 Dia.	3.48 - 4.24 Dia.
D	.295 - .305	7.49 - 7.75
E	.037 - .043 Dia.	.94 - 1.09 Dia.
F	1.0 Min.	25.4 Min.
G	.195 - .205	4.95 - 5.21

